

Measurements and Simulations of the Brighter-Fatter Effect in CCD Sensors

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December 2, 2016

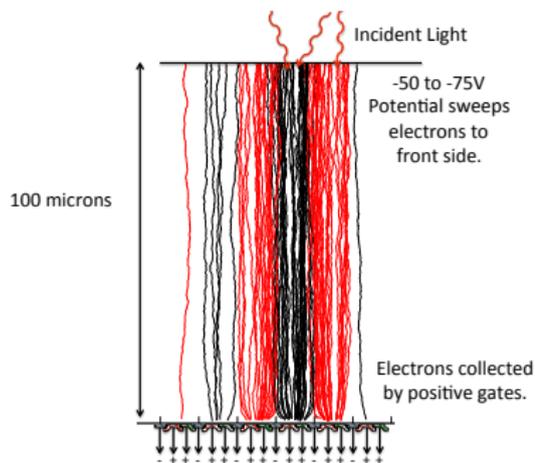
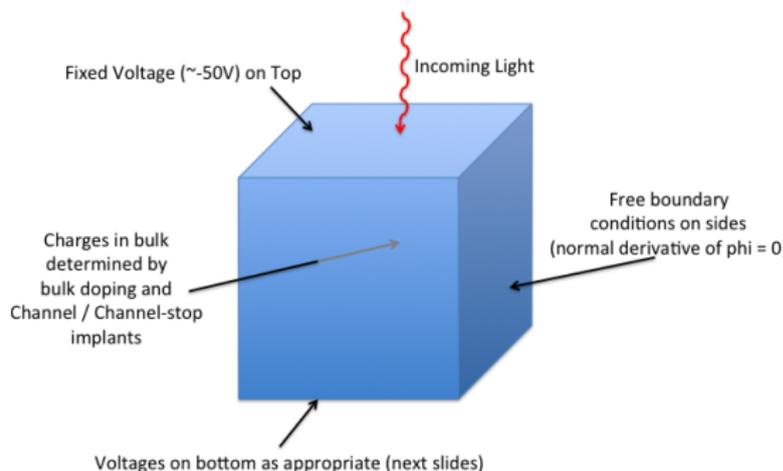
Acknowledgements:

Tony Tyson, Andrew Bradshaw, Kirk Gilmore, Perry Gee

Outline

- Solving for potentials and fields.
- Tracking electrons in the lattice.
- Spot size measurements and simulations.
- Pixel distortions and pixel-pixel correlations.
- Modeling saturation effects.
- Conclusions and next steps.

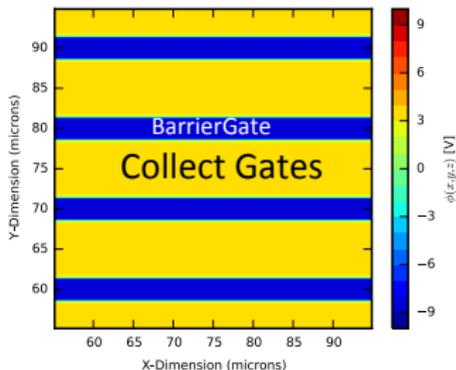
Typical Simulation 100 μm Cube.



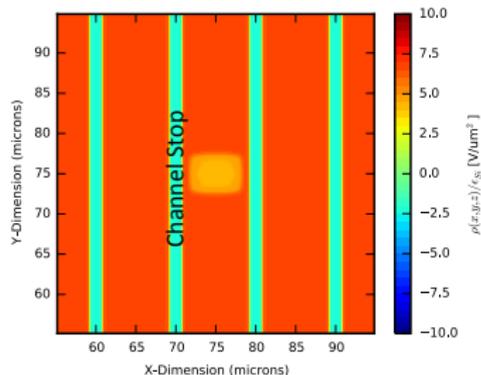
- Poisson's equation solved using multi-grid methods.
- 100 μm Cube. - 10 X 10 pixels in X and Y.
- 32 grid cells per pixel - cell size = 0.31 μ .
- Typical single core performance:
 - Poisson Solution ≈ 10 seconds.
 - Electron Tracking ≈ 300 e-/second.

Pixel Array Summary Plot

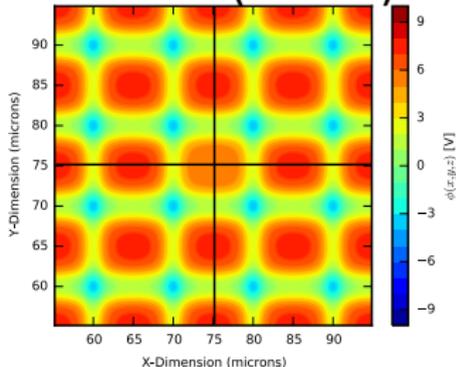
Potential($z=0$)



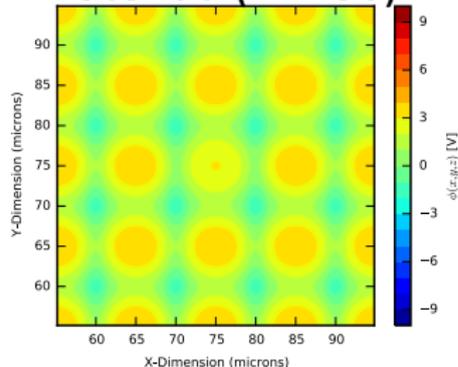
Charges



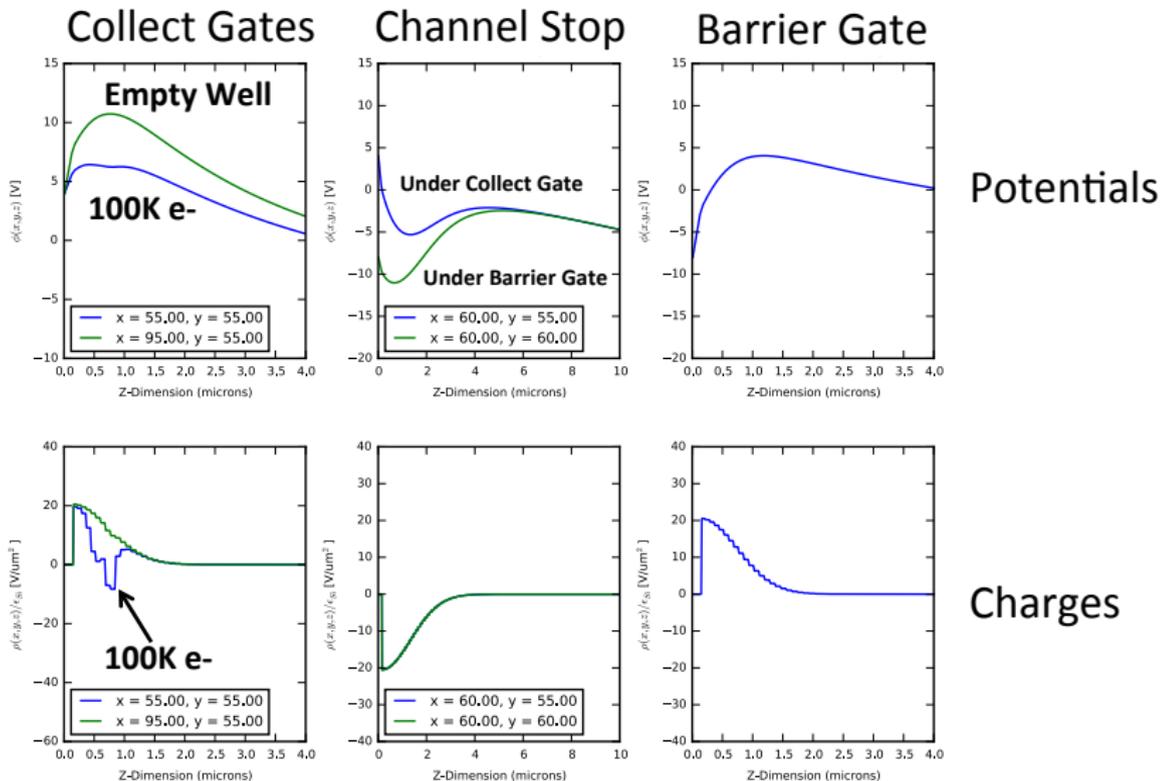
Potential($z=1.07$)



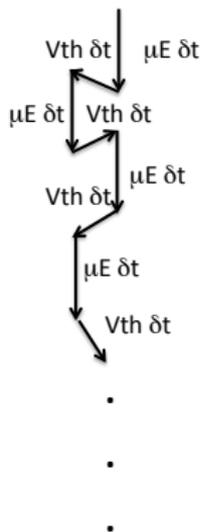
Potential($z=2.56$)



Pixel Region Charges and Potentials

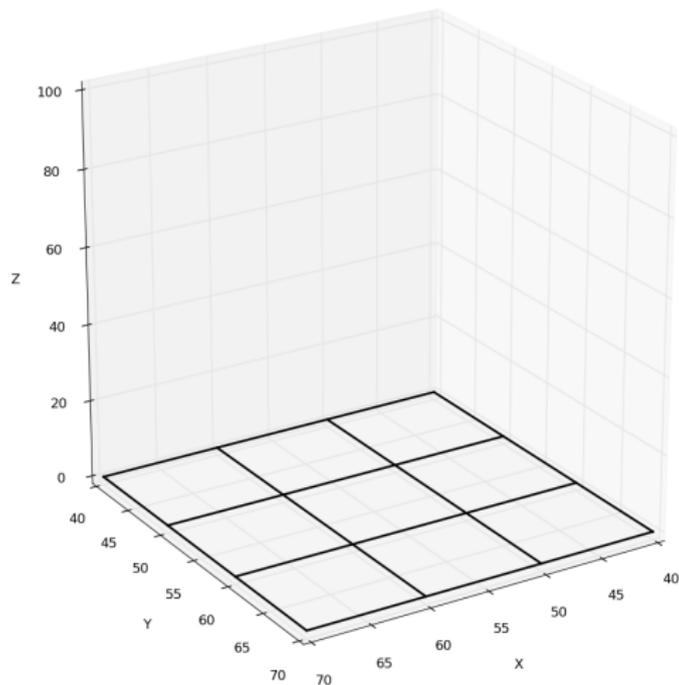


Diffusion Model

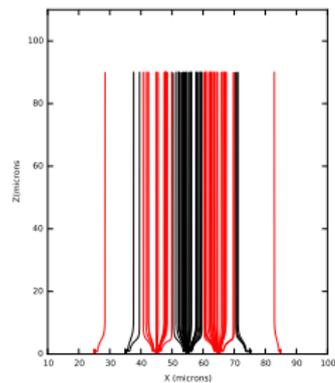
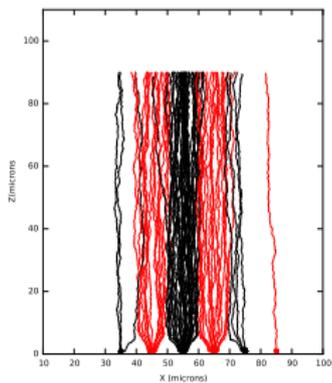
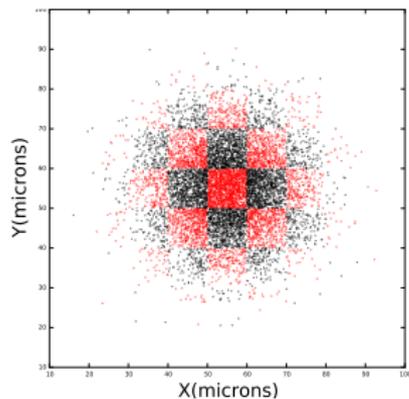
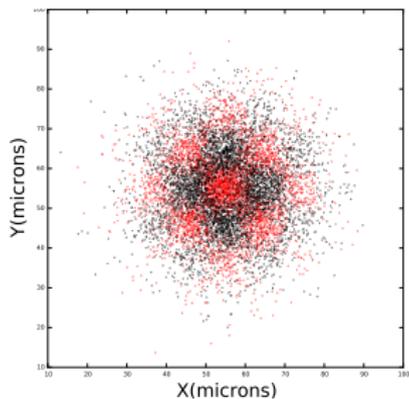


- Mobility: $\mu(E, T)$ calculated from Jacobini model
- $\mu = 1584 \frac{\text{cm}^2}{\text{V}\cdot\text{sec}}$ at $E = 6000 \frac{\text{V}}{\text{cm}}$
- Collision time:
 - $\tau = \frac{m_e^*}{q_e} \mu$
 - τ typically about 0.9 ps.
 - δt drawn from exponential distribution with mean of τ
- $V_{th} = \sqrt{\frac{3kT}{2m_e^*}}$
- $V_{th} \approx \mu E$
- Each thermal step in a random direction in 3 dimensions.
- Typically about 1000 steps to propagate to the collecting well.

Movie of Pixel Filling - First 10,000 Electrons



Impact of electron diffusion

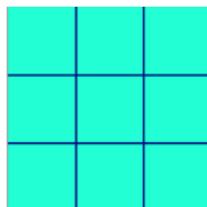
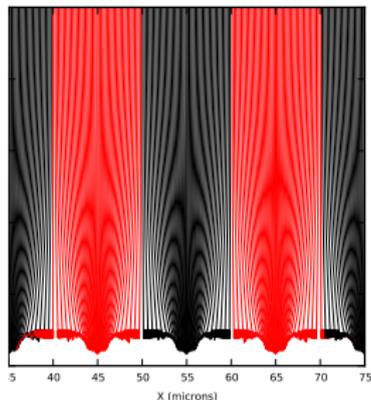


Theoretical Diffusion

Diffusion turned off

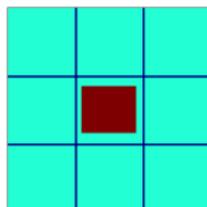
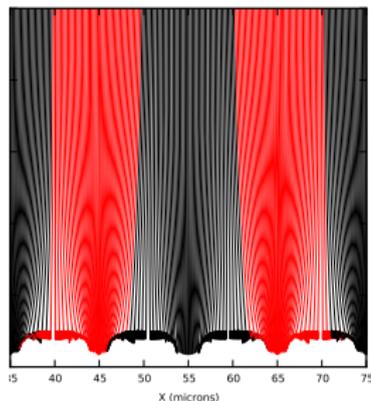
Basics of the Brighter-Fatter Effect

Diffusion turned off here.



Pixel empty of charge

Diffusion turned off here.

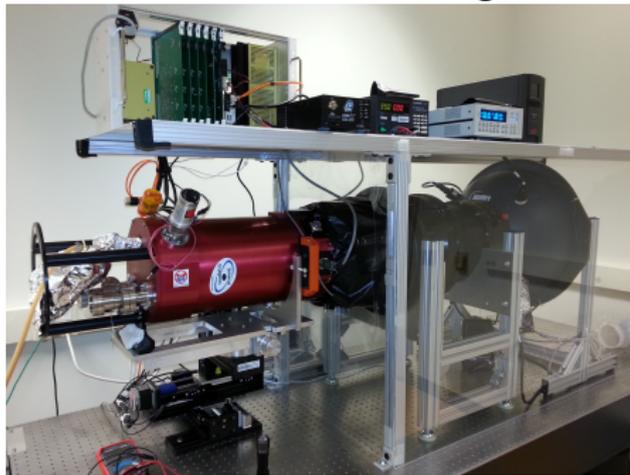


Pixel with 100K e⁻

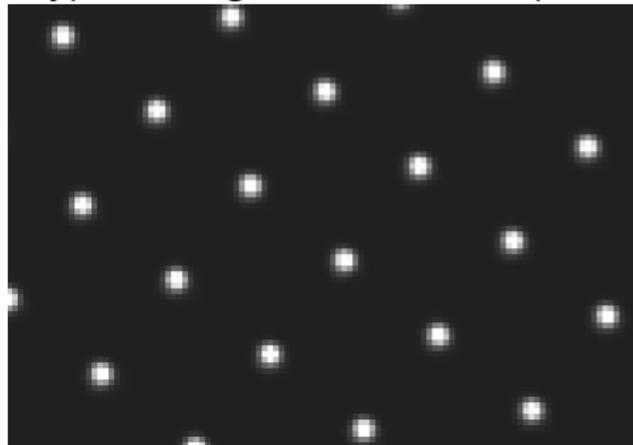
- Electrons stored in the potential well repel incoming electrons and push them into surrounding pixels.

LSST Optical Simulator and Typical Spot Images

UC Davis 1:1 Re-Imager

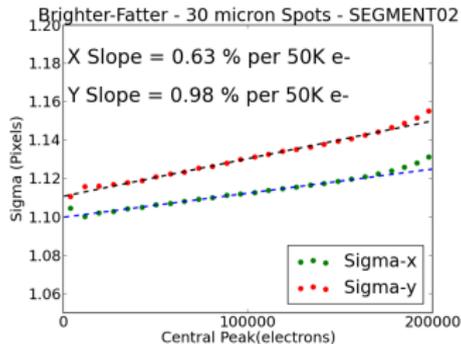


Typical Image of 30 micron Spots:

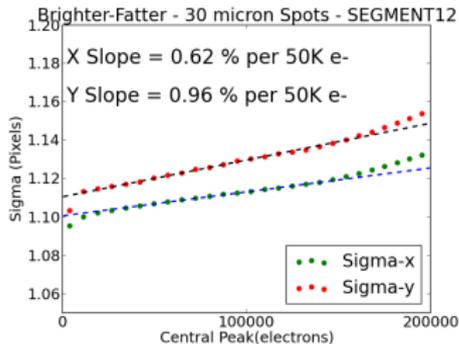


Tyson, et.al., "The LSST Beam Simulator", SPIE 9154-67 (2014), arXiv:1411.5667.

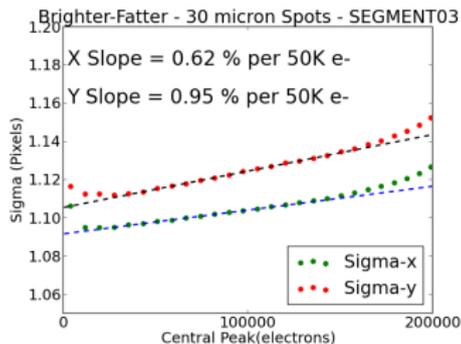
Typical Brighter-Fatter Effect Measurements - ITL 3800



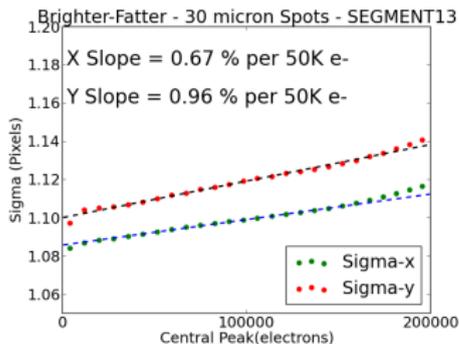
SEGMENT02



SEGMENT12



SEGMENT03



SEGMENT13

Many measurements have been made under different conditions.

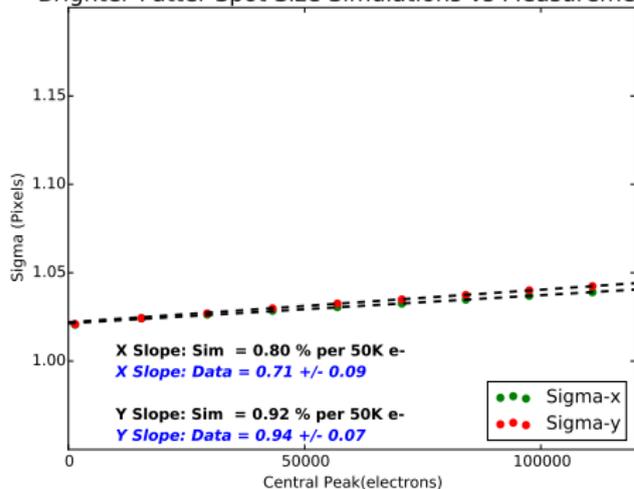
Simulation Strategy for B-F effect.

- Solve Poisson's equation for postage stamp with all pixels empty.
- Choose a random location within the central pixel.
- Determine starting locations for N electrons in a 2D Gaussian spot.
- Propagate these electrons down to their collecting gates.
- Re-solve Poisson's equation with these wells now containing the appropriate charge.
- Repeat with N more electrons.
- I have been using 10,000 electrons per step, which places about 1000 electrons in the central pixel, so about 100 iterations are needed to fill the central pixel.
- In practice, repeat for more than one spot (typically 64), each with a different central location.
- Typical run takes ≈ 6 hours.

Measurements vs Simulations

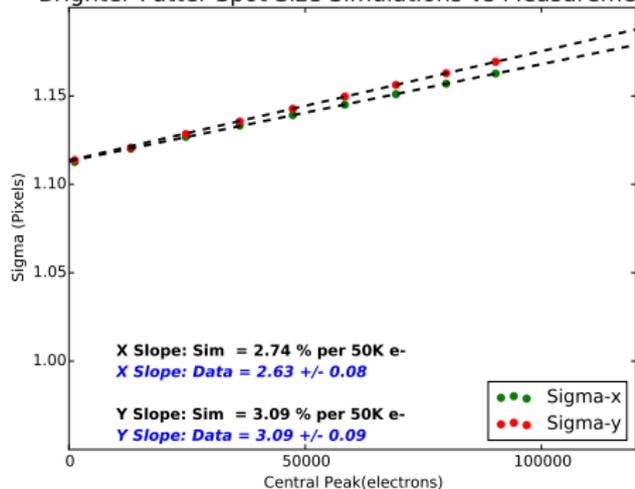
VBB = -60V

Brighter-Fatter Spot Size Simulations vs Measurements

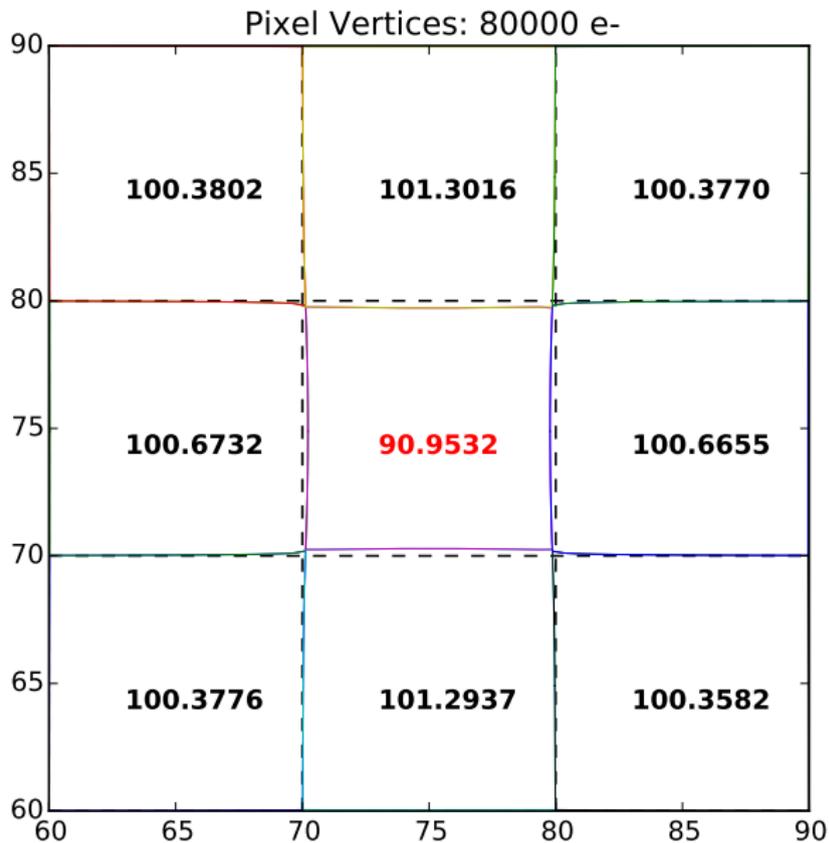


VBB = -10V

Brighter-Fatter Spot Size Simulations vs Measurements

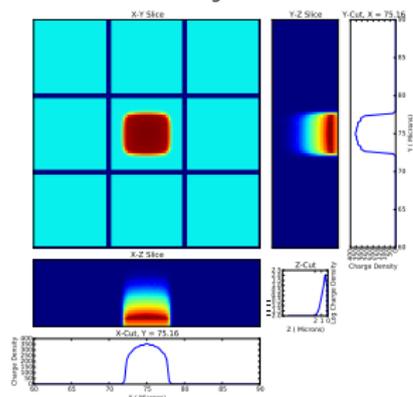


Pixel Shape Distortion due to Collected Charge

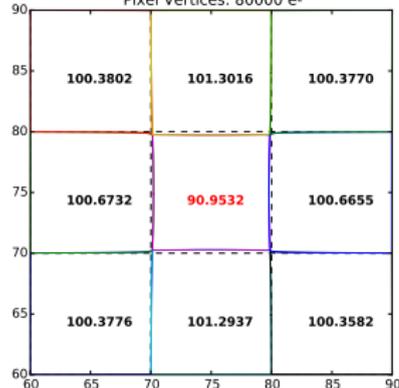


Pixel Areas and Correlations

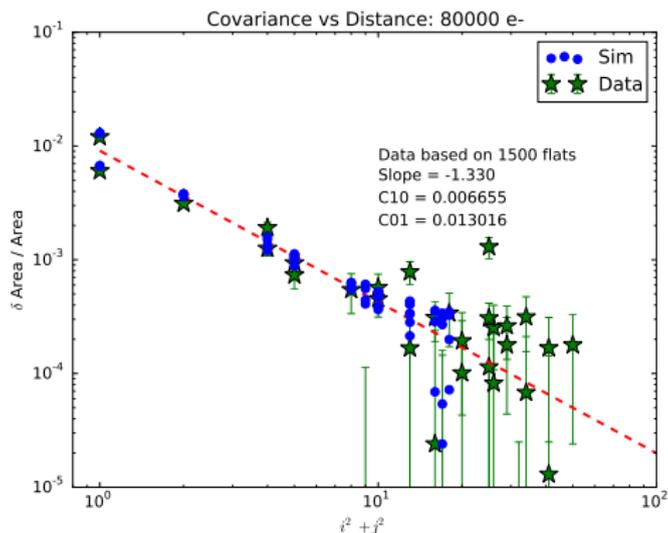
Electron Charge Distribution



Pixel Vertices: 80000 e-



Simulations vs ITL 3800 Measurements

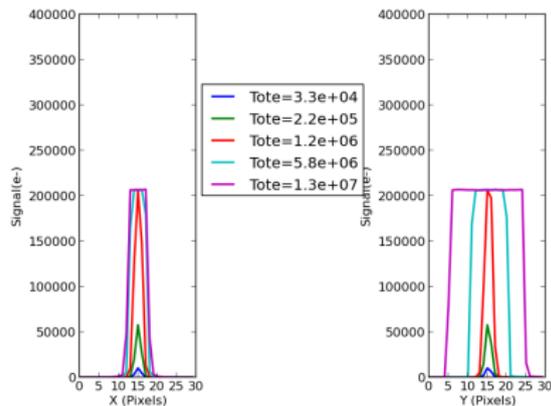


- Antilogus, et al., JINST 9C3048 (2014), arXiv:1402.0725.
- Rasmussen, A., JINST 904027 (2014), arXiv:1403.3317.

Saturated Spot Profiles

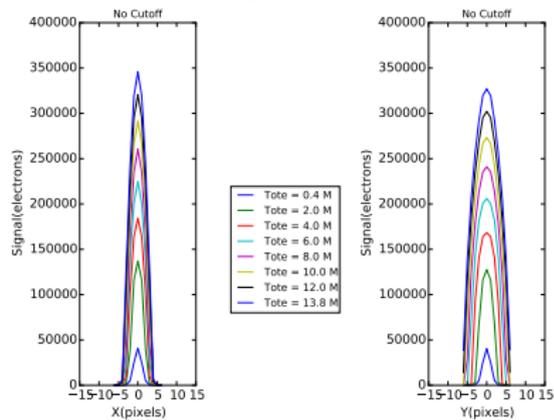
Measurements ITL 3800

Saturation Images vs Total Electrons $V_{pi} = -8, V_{ph} = -4, Ph = 2, Vog = 0$



Simulation

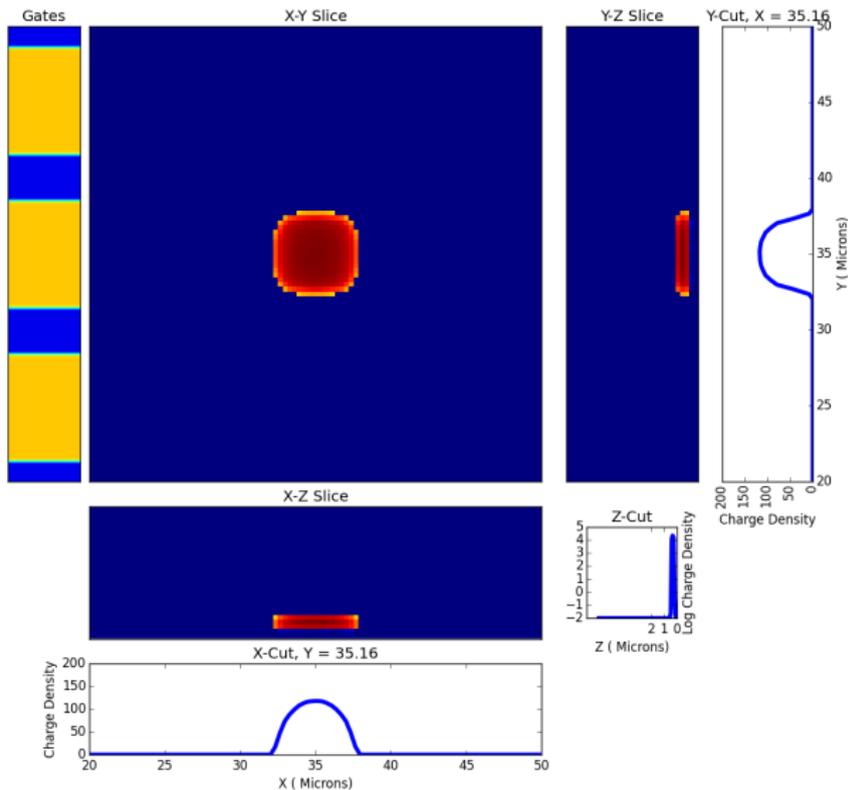
Saturation Images vs Total Electrons - Simulated



- Simulated profiles never flatten out.
- “Cutoff” may happen in charge transfer instead of charge collection, either in the array or outside the array in the serial transfer.

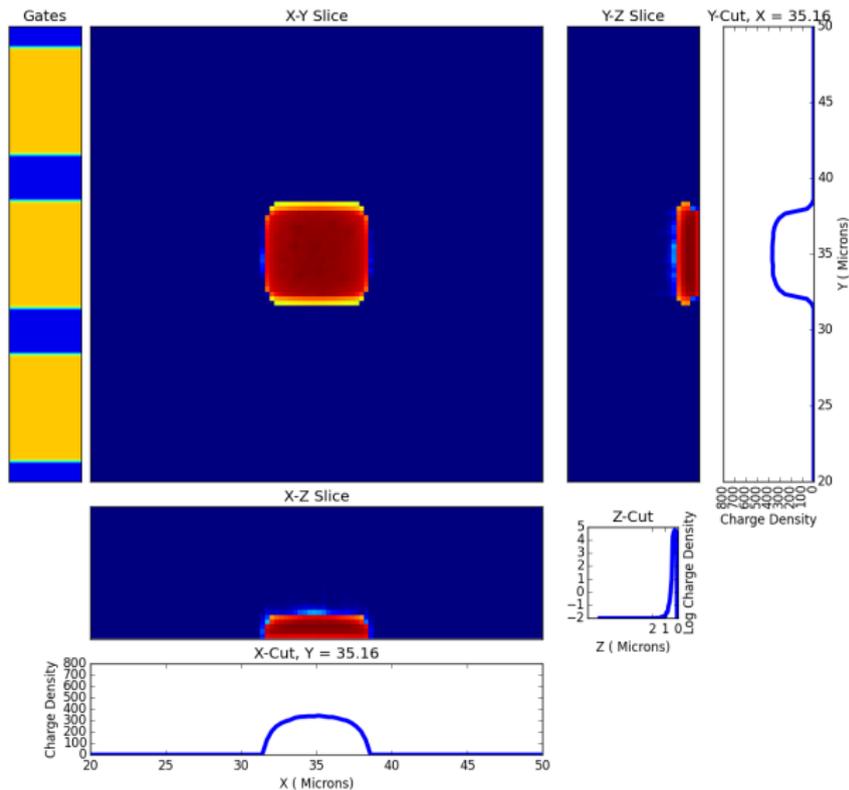
Movie of Charge Transfer - 50K Electrons

Electron Charge Distribution, $T=200$ ns



Movie of Charge Transfer - 200K Electrons

Electron Charge Distribution, $T=200$ ns

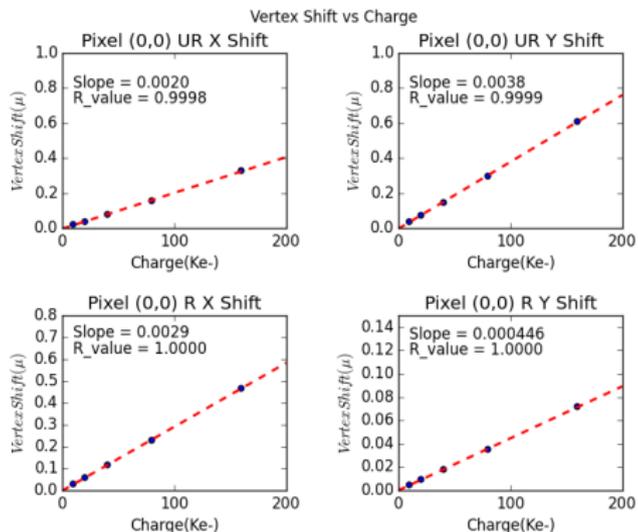
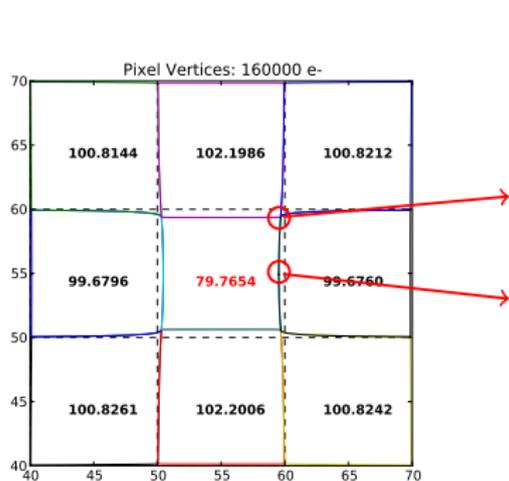


Conclusions and Next Steps

- We have had good success in simulating the Brighter-Fatter Effect:
 - Direct Spot Size Measurements.
 - Pixel Correlation Measurements.
- Biggest uncertainty concerns state of channel stop region:
 - Best fits to measurements obtained with the assumption that the channel stop region is not fully depleted, but contains free holes. However, I am still uncertain of this conclusion.
 - Plan to obtain physical measurements (SIMS) of dopant profiles.
- Simulations are not fitting saturation full well effects:
 - Attempting to determine how much of full well effect is due to charge collection, and how much is due to charge transfer.
- Latest code, with documentation and examples, is at:
https://github.com/craiglagegit/Poisson_CCD22

Back-Ups

Pixel Vertex Movement with Charge



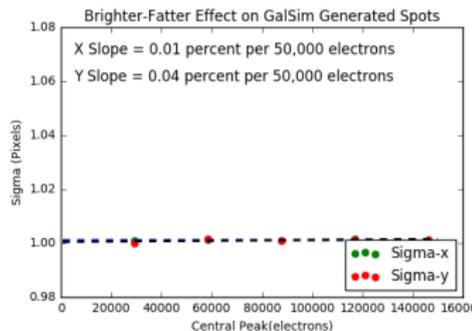
Linear relationship of vertex motion with charge implies superposition should work.

Superposition Strategy

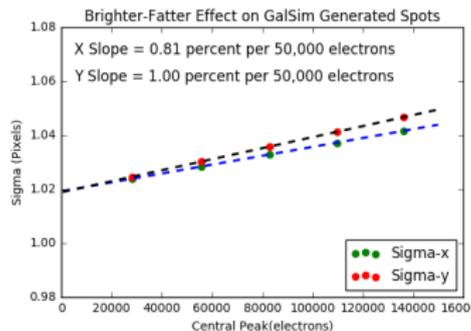
- If superposition works, we can do the following:
 - Solve (one time) Poisson's equation with one pixel containing N electrons, all surrounding pixels empty.
 - Determine displacement of pixel vertices (out to $\pm M$ pixels away) per electron.
 - For general case where many pixels contain a varying amount of charge, sum up vertex displacements to determine pixel vertices.
 - For what follows, went up to 4 pixels away, and used 260 vertices / pixel (4 corners + 64 vertices per edge). This is probably more resolution than is needed.

GalSim Comparisons - Calculate pixel distortions every 10,000 photons

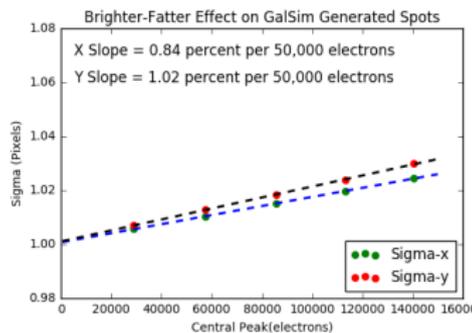
No B-F Effect



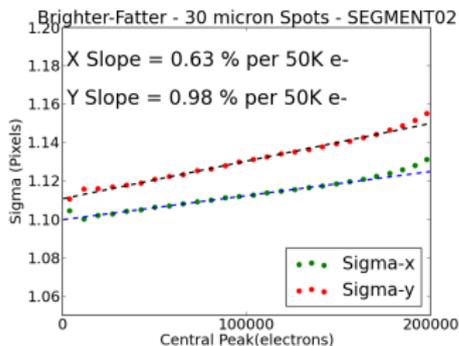
With B-F, With Diffusion



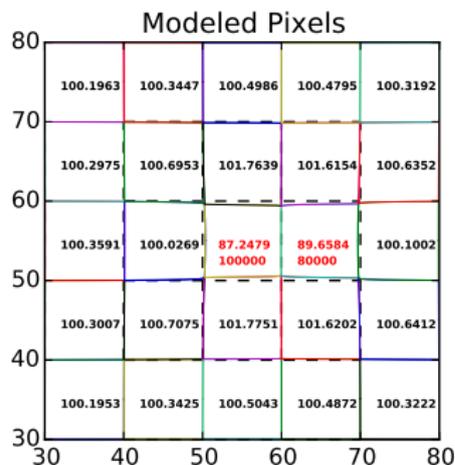
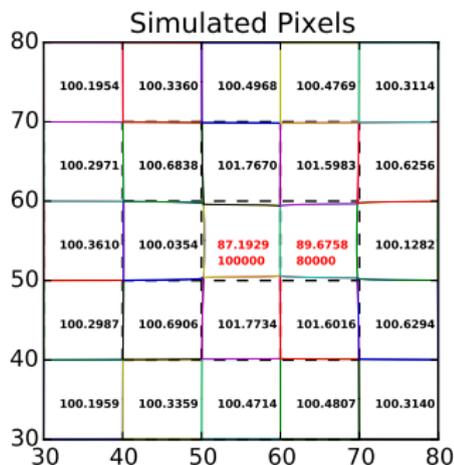
With B-F, No Diffusion



Measurements



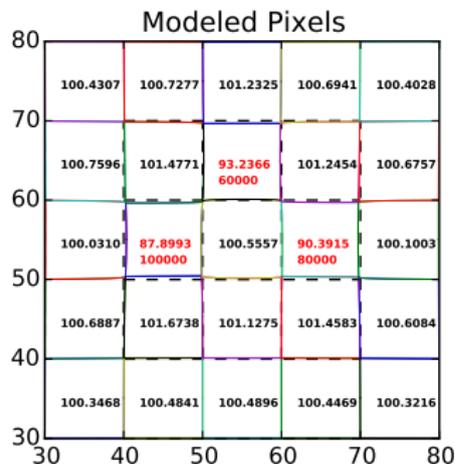
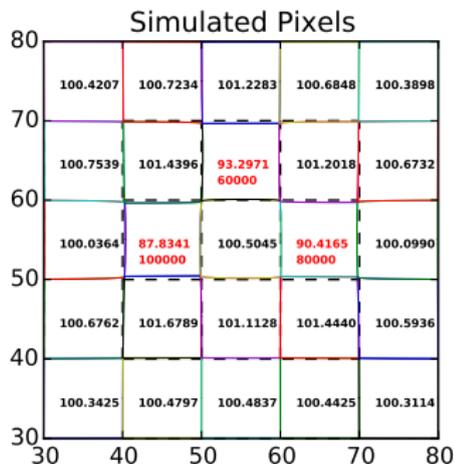
Superposition Test 1



Average Area Error = 0.0139 percent
Average Vertex Error = 0.0003 microns
Worst Case Area Error = 0.0551 percent
Worst Case Vertex Error = 0.0669 microns

- Left - Full Physics-based simulation, solving Poisson's equation and finding pixel vertices through binary search. Simulation Time - 10's of minutes.
- Right - Take pixel vertex displacement from a single Physics-based run with one pixel containing 80K e-, and superpose the displacements for the two pixels containing charge. Simulation Time - \ll 1sec.

Superposition Test 2



Average Area Error = 0.0242 percent
Average Vertex Error = 0.0003 microns
Worst Case Area Error = 0.0682 percent
Worst Case Vertex Error = 0.0638 microns

- Left - Full Physics-based simulation, solving Poisson's equation and finding pixel vertices through binary search. Simulation Time - 10's of minutes.
- Right - Take pixel vertex displacement from a single Physics-based run with one pixel containing 80K e-, and superpose the displacements for the three pixels containing charge. Simulation Time - \ll 1sec.